



# Paint it Black – Increase WSN Energy Efficiency with the Right Housing

RealWSN 2015

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# Introduction

## Many WSNs in challenging areas of application

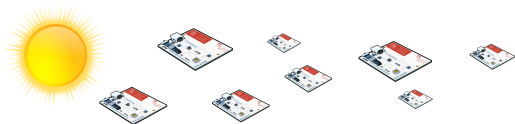
- Harsh environmental conditions  
→ Reliability of nodes decreases
- Bad maintainability  
→ Constrained energy resources (e.g. batteries)



# Temperature vs. Reliability vs. Energy Efficiency

The crux: Higher temperatures...

1. might disturb wireless communication [1, 2, 3]



Boano et.al., *The Impact of Temperature on Outdoor Industrial Sensor-net Applications*, IEEE Industrial Informatics, 2010



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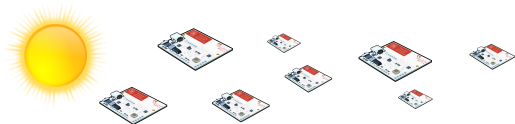
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# Temperature vs. Reliability vs. Energy Efficiency

## The crux: Higher temperatures...

1. might disturb wireless communication [1, 2, 3]
2. lead to *increased energy efficiency*

→ Q: How does temperature affect the energy efficiency of a node?



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# Undervolting – Basics

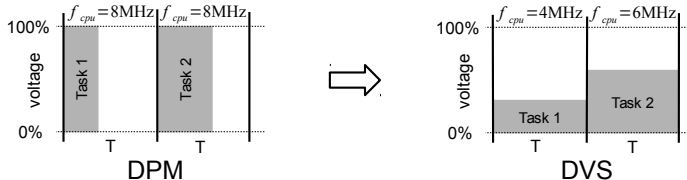
## Voltage Scaling increases energy efficiency significantly

- Dynamic power dissipation of CMOS  $p_{dyn} = C_L \cdot f_{cpu} \cdot V^2$

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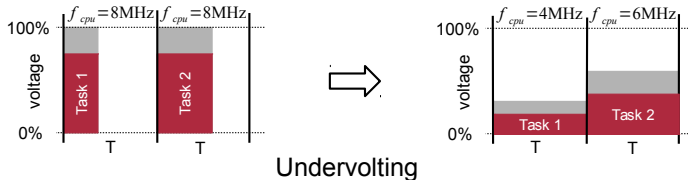
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- DVS: Adapting  $f_{cpu}$  to current workload *and* scale  $V(f_{cpu})$



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- DVS: Adapting  $f_{cpu}$  to current workload *and* scale  $V(f_{cpu})$
- Undervolting: Violate specifications  $V(f_{cpu}) \rightarrow V(f_{cpu}) - \Delta V$



# Undervolting – Legitimation

## Temperature dependency of CMOS gates

- Specification of  $V(f_{cpu})$  is given in data sheets
- Specification does *not* include the temperature  $V(f_{cpu}, T)$ 
  - Threshold Voltage  $V_{th}$  of CMOS is temperature-dependent

$$V_{th}(T) = V_{th0} + \alpha \cdot (T - T_0)$$

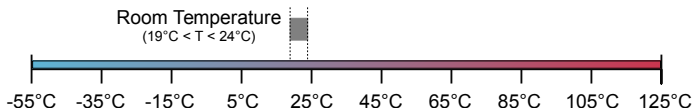
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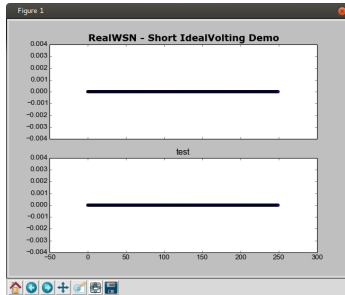
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MCUs cover a widespread temperature range with a fixed  $V(f_{cpu})$



→ MCUs must be able to run below  $V(f_{cpu})$  (under *normal* conditions)

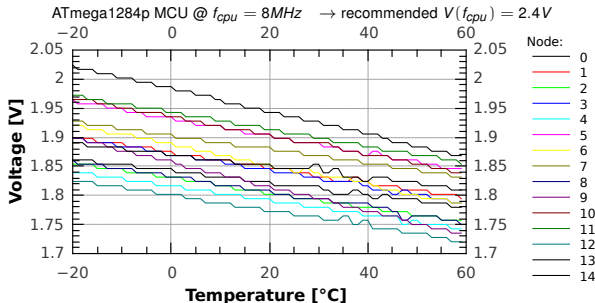
# Short Demo



# First Results – Temperature Dependency

## Measurement of $v(T)$ in a climatic chamber

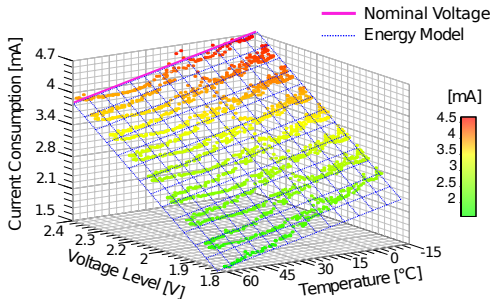
- Higher temperatures allow lower voltage levels
- Heterogeneity due to manufacturing and temperatures



# First Results – Energy Model

## Measurement of $I_{CC}(v, T)$ in a climatic chamber

ATmega1284p MCU @  $f_{cpu} = 8MHz$  transceiver unit in sleep mode

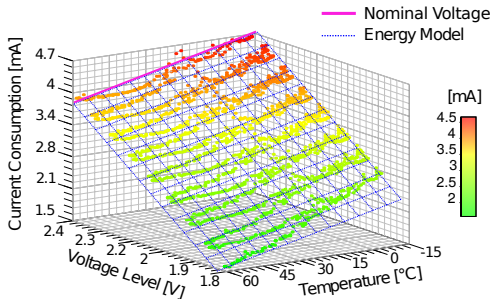




# First Results – Energy Model

## Measurement of $I_{CC}(v, T)$ in a climatic chamber

ATmega1284p MCU @  $f_{cpu} = 8MHz$  transceiver unit in sleep mode



- Derivation of an energy model  $I_{CC}(v, T) = p + s \cdot T + t \cdot v$

least squares method leads to  $p = -4.558 [mA]$ ,  $s = -11.976 [\mu AK^{-1}]$  and  $t = 3.770 [mAV^{-1}]$

# Experiment

Idea: Quantify the energy saving potential of housings

1. Measurement of thermal characteristics of different housings
2. Simulate the energy consumption by using  $v(T)$  and  $I_{CC}(v, T)$

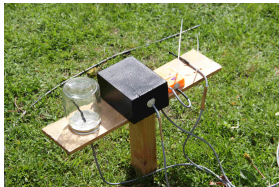
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## Setup: Four different housings at different locations

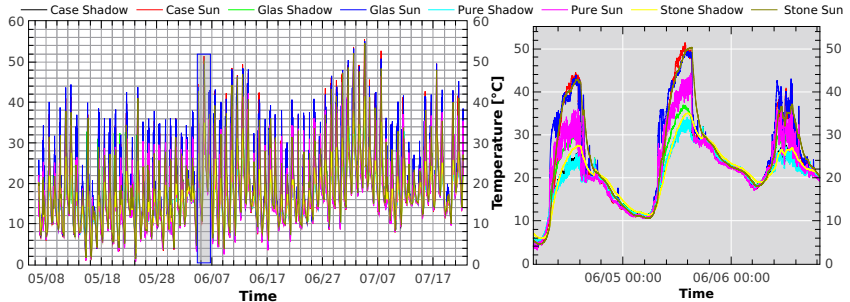
- Housings – Unpacked (pure), Plastic (case), Transparent (glass), Stone
- Locations – Direct sunlight (☀) and shadow (●)



# Experimental Results – Temperature profile

## Long-term temperature measurement in northern Germany<sup>a</sup>

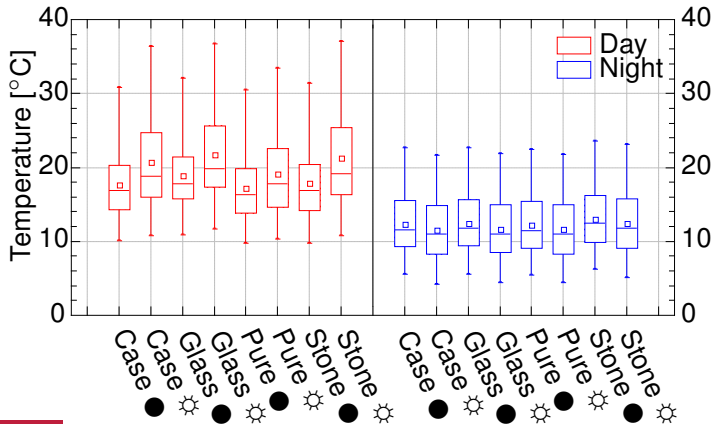
<sup>a</sup> → Online: [www.ibr.cs.tu-bs.de/users/kulau/PotatoNet-heat.html](http://www.ibr.cs.tu-bs.de/users/kulau/PotatoNet-heat.html)



# Experimental Results – Characteristics

## Thermal characteristics during day and night

→ Average temperature – remarkable difference during daytime



# Experimental Results – Energy Consumption

## Energy Consumption [J] (dawn to dusk)

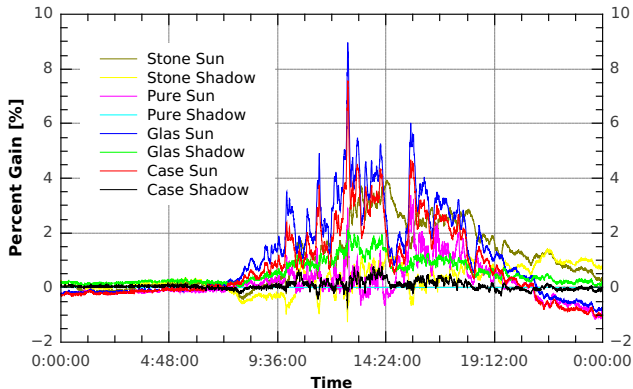
→ Housing and location influences the energy efficiency

	Undervolted		Nominal Voltage	
	hot day	cold day	hot day	cold day
Case ●	323.76	376.83	852.46	902.86
Case ☀	313.07	374.58	843.63	901.05
Glass ●	320.99	374.26	850.17	900.90
Glass ☀	312.73	372.04	843.27	899.10
Pure ●	325.06	377.99	853.54	903.80
Pure ☀	318.94	376.02	848.44	902.32
Stone ●	322.68	377.95	851.67	903.87
Stone ☀	312.05	374.87	842.79	901.38

# Experimental Results – Exemplary Day

Gain in energy efficiency (baseline = pure shadow)

→ Significant differences between location and housings



# Summary

## WSNs in harsh environments:

- Potential for increased energy efficiency
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  - $\approx 4\%$  between housings (single day)
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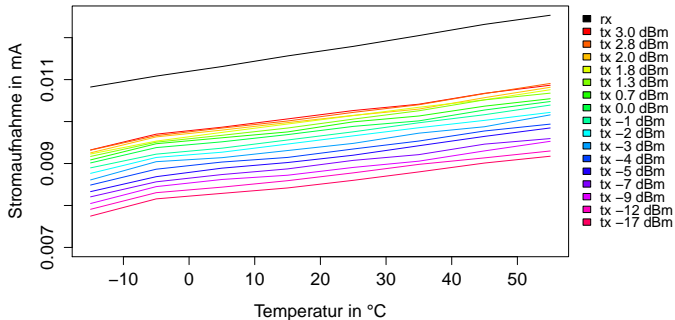
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**Thank you for your attention! Questions?**

Ulf Kulau

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# Backup – Transceiver vs. Temperature



# Backup – Protocols

